## The Combined Effects for PXR

## at Channeling

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## > Combined effects for PXR: PXRC and DCR

> PXRC: PXR from channeled electrons (positrons) - arises as very special kind of DCR (diffracted channeling radiation).
> PXRC: quantum effect connected with "transverse" form-factor of channeled electron (positron) $\rightarrow$ modification (quantum correction) of angular distribution of emitted X-ray photons compared to ordinary PXR.
> PXRC: orientation dependence on angle of incidence into a crystal (relative to the channeling planes)
> PXRC: dependence on initial beam energy (number of quantum sub-barrier channeled states)
$>$ SAGA-LS: first experiment devoted to PXRC observation

## The formation of DCR

- Emission of virtual CR-photon by channeled electron (positron) due to spontaneous transition $i \rightarrow f$
- Virtual CR-photon Bragg diffraction on the crystallographic planes
- Virtual CR-photon transformation into a real photon


The Feynman diagram for DCR in a first order in $\alpha$ (fine-structure constant) and diagram of diffraction.

## RRGESOMI

## Scheme of the DCR formation at axial channeling



## Cross-section of the DCR

$$
d \sigma=\frac{2 \pi}{\hbar}\left|M_{i f}\right|^{2} \delta\left(\hbar \omega-\left(E_{i}-E_{f}\right)\right) d \rho_{f}
$$

$M_{i f}$ is the DCR matrix element,

$$
\begin{gathered}
M_{i f}=-e\left\langle\Psi_{f}(\vec{r})\right| \vec{A}^{*}(\vec{r}) \vec{\alpha}\left|\Psi_{i}(\vec{r})\right\rangle \\
\vec{A}(\vec{r})=\sum_{\kappa}\left(\vec{A}_{o \kappa} \exp (\mathbf{i} \vec{k} \vec{r})+\sum_{g \neq 0} \vec{A}_{g \kappa} \exp [\mathbf{i}(\vec{\kappa}+\vec{g}) \vec{r}]\right), \\
M_{i f}^{(-g) r}=-e C_{i f}\left(C_{i}+C_{f}\right) \vec{\varepsilon}_{g r} \vec{I}_{i f} / 2 m c, \\
\vec{I}_{i f}= \\
\left.(2 \pi / L)^{N} A_{g \kappa}^{\tau_{\kappa}^{*}}\left\langle\varphi_{f}\left(\vec{r}_{\perp}\right)\right| \hat{\vec{p}}\left|\varphi_{i}\left(\vec{r}_{\perp}\right)\right| \operatorname{Exp}\left(-\mathbf{i} \vec{\kappa}_{-g \perp} \vec{r}_{\perp}\right)\right\rangle_{\perp} \\
\times \delta\left(\Delta \vec{p}_{i f \|} / \hbar-\vec{\kappa}_{-g \|}\right), \\
C_{i f}= \\
C_{i}=c^{2} m\left(E_{i}+c^{2} m / E_{f} \sqrt{1+c^{2} m / E_{i}},\right.
\end{gathered}
$$ (the Bloch function)

$M_{i f}^{(-g) \tau}$ is the DCR matrix element
$\vec{\varepsilon}_{g 7}$ is the polarization vector
$\vec{g}$ is the reciprocal lattice vector
( $N=1$ for the case of axial channeling and $N=2$ for the case of planar channeling)

## DCR matrix element

At the channeling condition $E_{\|} \gg U\left(r_{\perp}\right) \quad E_{\| \|} \cong E_{\| f}$.

DCR matrix element

$$
\begin{aligned}
\left.\sqrt{2(1+}+W_{\tau}^{2}\right) & M_{i f}^{(-g) \tau}= \\
& =-C_{i f} C_{i}(2 \pi / L)^{N} \frac{e}{m c} A_{i \sigma}^{\tau}\left(\vec{\varepsilon}_{g \tau \|} \vec{p}_{i \|} F_{i f}-\mathbf{i} m \gamma \Omega_{i f} \vec{\varepsilon}_{g r \mid} \vec{\Delta}_{i f}\right) \\
& \times \delta\left(\Delta \vec{p}_{i f \|} / \hbar-\vec{\kappa}_{-s\| \|}\right) .
\end{aligned}
$$

$$
\begin{aligned}
& \vec{\Delta}_{i f}=\left\langle\varphi_{f}\left(\vec{r}_{\perp}\right)\right| \vec{r}_{\perp} \exp \left(-\mathbf{i} \overrightarrow{\boldsymbol{K}}_{-8 \perp} \vec{r}_{\perp}\right)\left|\varphi_{i}\left(\vec{r}_{\perp}\right)\right\rangle_{\perp}, \\
& F_{i f}=\left\langle\varphi_{f}\left(\vec{r}_{\perp}\right) \exp \left(-\mathbf{i} \vec{\kappa}_{-8 \perp} \vec{r}_{\perp}\right) \mid \varphi_{i}\left(\vec{r}_{\perp}\right)\right\rangle_{\perp}, \\
& \Omega_{i f}=\left(E_{i \perp}-E_{f \perp}\right) / \hbar .
\end{aligned}
$$

## DCR matrix element spontaneous intraband transition

Matrix element with $i=f$

$$
\begin{aligned}
\sqrt{2\left(1+W_{\tau}^{2}\right)} M_{i i}^{(-g) \tau}= & -C_{i i} C_{i}(2 \pi / L)^{N} \frac{e}{m c} A_{0 \kappa}^{\tau} \vec{\varepsilon}_{g \tau \|} \vec{p}_{i \|} F_{i i} \\
& \times \delta\left(\Delta p_{i \|} / \hbar-\vec{\kappa}_{-g\| \|}\right) .
\end{aligned}
$$

Angular distribution of this part of DCR

$$
\frac{d^{3} N}{d \theta_{x} d \theta_{y} d z}=\frac{\alpha \omega_{B}}{4 \pi c \sin ^{2} \theta_{B}} F_{i}^{2}\left[\frac{\theta_{x}^{2}}{4\left(1+W_{\pi}^{2}\right)}+\frac{\theta_{\theta}^{2}}{4\left(1+W_{\sigma}^{2}\right)}\right]
$$

In the well known formula for the angular distribution of PXR [1] "transverse" formfactor $F_{i i}$ is absence

## PXRC is special case of DCR

 and its amplitude is always smaller than the amplitude of PXR $\left(F_{i i}<1\right)$
## Angular distribution of the PXRC and PXR

 electron beam with energy 255 MeV at (220) Si channeling

## Preliminary experimental results on PXRC

## $255 \mathrm{MeV} e^{-} \rightarrow 20-\mu \mathrm{m}$-thick Si crystal


(220) planar channeling


The experimental data obtained at SAGA Light Source (Japan)

## Preliminary experimental results on PXRC

## $255 \mathrm{MeV} e^{-} \rightarrow 20-\mu \mathrm{m}$-thick Si crystal




Angular divergence of the electron beam

$$
w\left(k_{o}\right)=\operatorname{Exp}\left[-k_{o}^{2} / 2 \sigma^{2}\right],
$$

$w$ is the probability that angle between channeling plane and the electron momentum equals $\theta_{0}=$ $k_{\mathrm{o}} \theta_{\mathrm{C}}$ ( $\theta_{\mathrm{C}}$ is critical channeling angle) $\sigma$ is the dispersion in $\theta_{\mathrm{C}}$ units

$$
\left.\frac{d^{3} N_{P X R C}}{d \theta_{x} d \theta_{y} d z}\right|_{\text {beam }}=\left\langle w\left(\theta_{o}\right) P\left(i, \theta_{o}\right) W_{P X R C}\left(i, \theta_{o}\right)\right\rangle_{\theta_{o}},
$$

$W_{\text {PXRC }}\left(i, \theta_{\mathrm{o}}\right)$ angular distribution of PXRC due to one electron,
$P\left(i, \theta_{\mathrm{o}}\right)$ is the initial population of the $i^{\text {th }}$ level for the electron incident at the angle $\theta_{0}$ to the channeling plane
$\langle\ldots\rangle_{\theta 0}$ - averaging over the angle $\theta_{0}$
Only the part of the electrons are captured to the channeling regime (that is to the sub-barrier levels) and its involved to the generation PXRC the other electrons generate the general PXR

$$
\left.\frac{d^{3} N}{d \theta_{x} d \theta_{y} d z}\right|_{\text {beam }}=\left.\frac{d^{3} N_{P X R C}}{d \theta_{x} d \theta_{y} d z}\right|_{\text {beam }}+\left\langle w\left(\theta_{o}\right) W_{P X R}\left(1-P\left(i, \theta_{o}\right)\right\rangle_{\theta_{o}},\right.
$$

## Angular distribution of the PXRC

electron beam with energy 255 MeV at (220) Si channeling


## Angular distribution of the PXRC

electron beam with energy 255 MeV at (220) Si channeling


## Conclusions

- Preliminary experimental results (SAGA-LS Linac) on angular distributions of PXR from channeling electrons with energy 255 MeV show small deviations from ordinary PXR angular distribution
- Probably, the deviations are explained by manifestation of the new Combined effect for PXR at channeling, i.e. by PXRC: quantum effect connected with "transverse" form-factor of channeled electron (positron) which leads to modification (quantum correction) of angular distribution of emitted X-ray photons compared to ordinary PXR.
- Further experiments at SAGA-LS are planned using thinner crystal and changing electron beam energy


## Thank you for attention

## RREQSOM

## Two-dimensional X-ray detector

Imaging plate [BaFX:Eu2+ $(\mathrm{X}=\mathrm{Cl}, \mathrm{Br}, \mathrm{I})$ ]

- Reusable
- Digitally readable
- Size: $20 \times 20 \mathrm{~cm}$
- Nominal position resolution: $50 \mu \mathrm{~m}$

Imaging plate reader [FUJIFILM BAS-2500]

Imaging plate eraser


